

Advanced Materials Modeling:
**Statistical mechanics and *ab initio* atomistic
thermodynamics**

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Thermodynamics

□ Why thermodynamics for materials?

A material is a collection of a large number of particles -- statistics starts to play a significant role at finite T

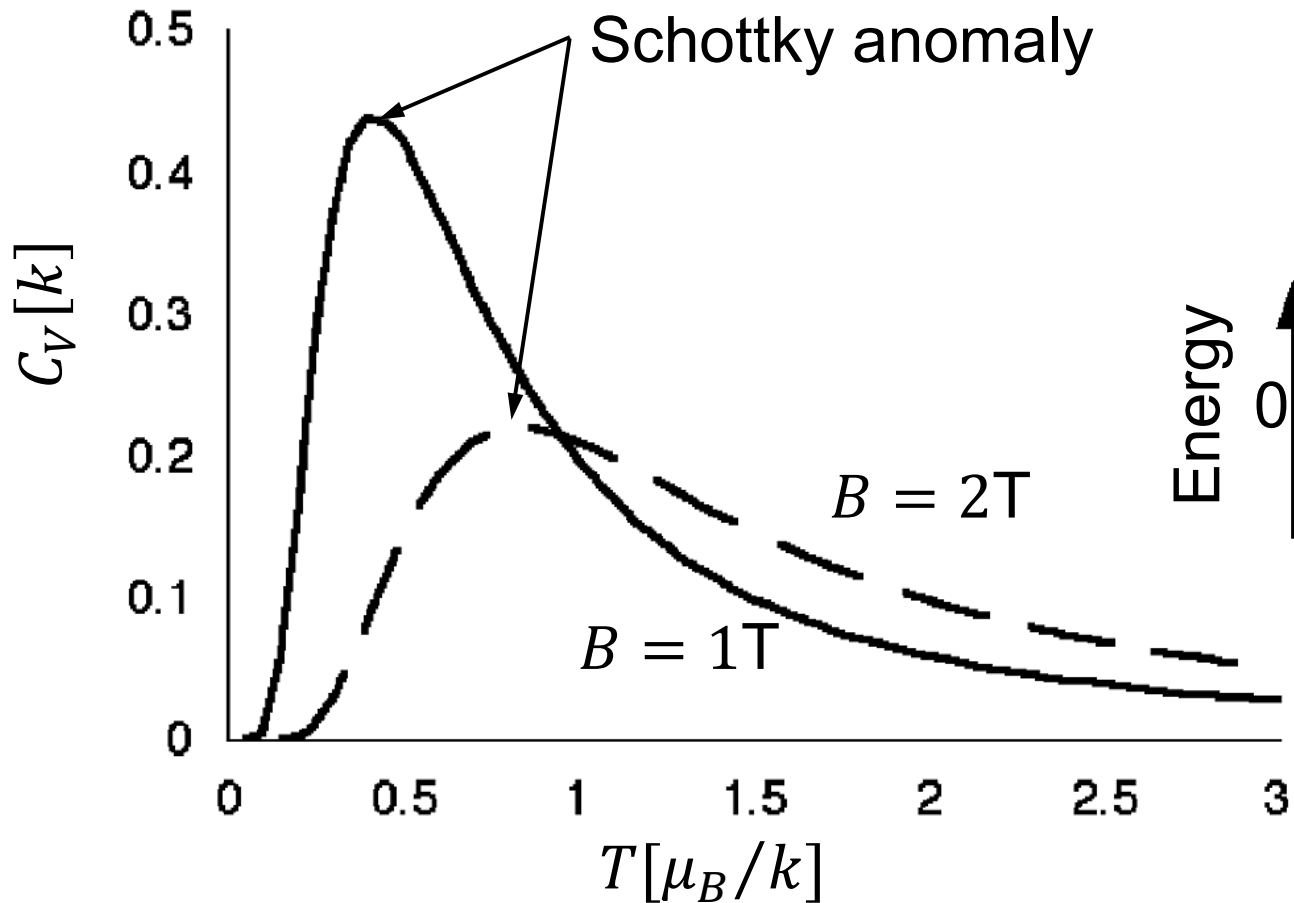
Thermodynamics determines defect concentrations and phase transformations, and influences magnetic properties, surface reactions, and crystal growth (the latter two are controlled by *kinetics*)

There is always a particle exchange between the material and its environment at finite T

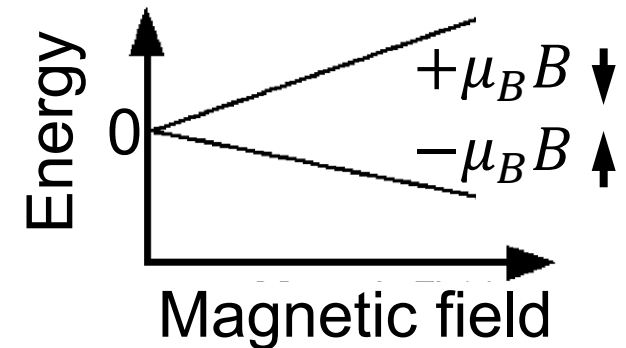
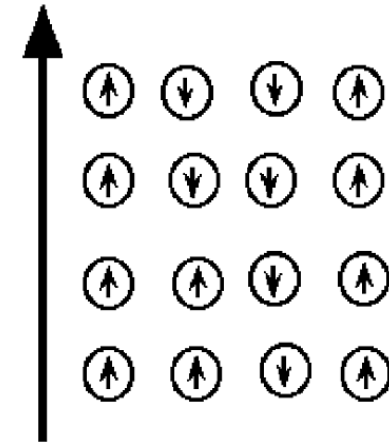
Thermodynamics

□ Example: Spins

Heat capacity of a paramagnet



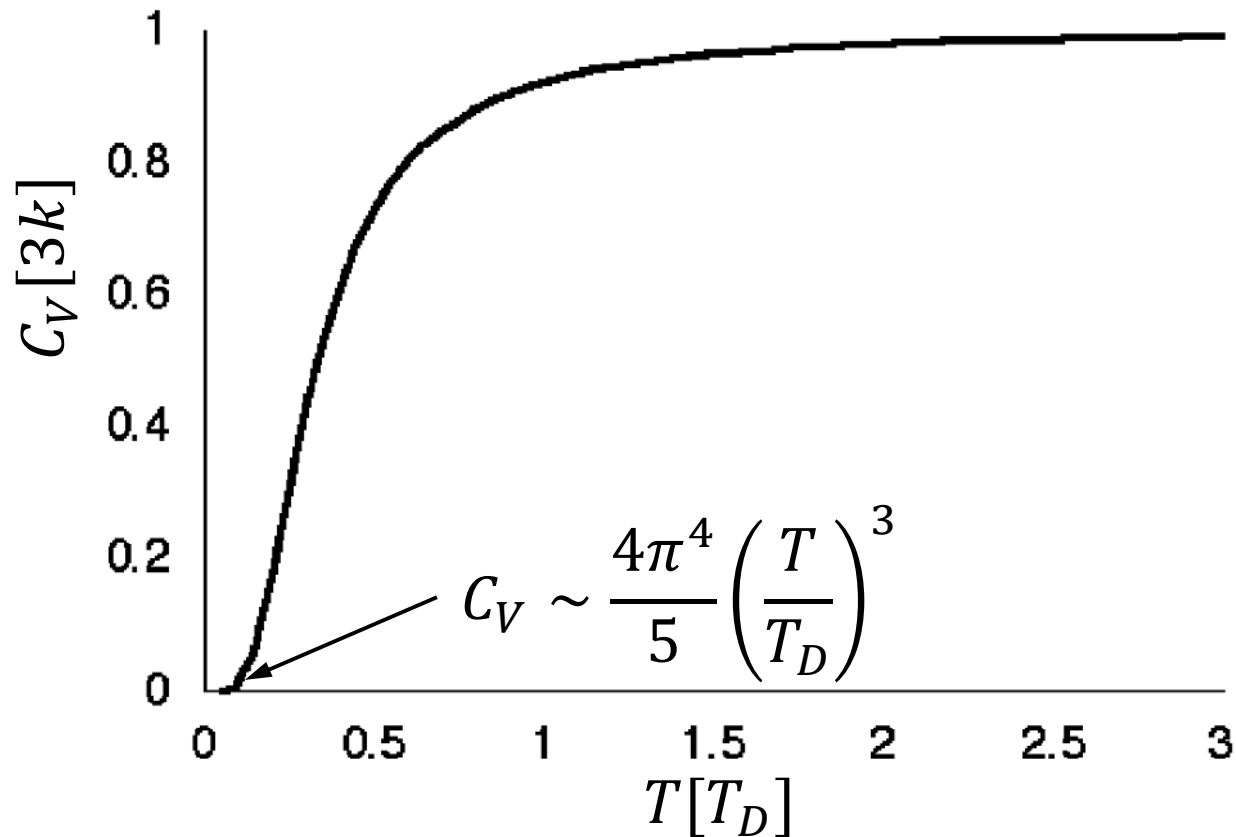
B-field



Thermodynamics

□ Example: Phonons

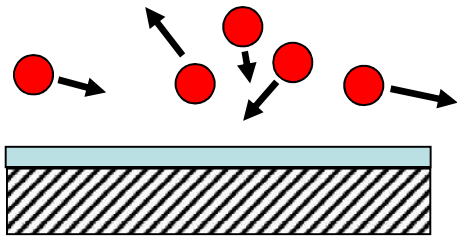
Heat capacity of a solid (Debye model - phonons in a box)



Thermodynamics

□ Example

Consider a metal surface in an oxygen atmosphere



$$\nu = \frac{p}{\sqrt{2\pi mkT}}$$

For $T = 300 \text{ K}$, $p = 1 \text{ atm} \rightarrow \nu \sim 10^8 \text{ site}^{-1} \text{ s}^{-1}$



Requires $p \leq 10^{-12} \text{ atm}$
to keep a “clean”
surface clean; surface
can also lose atoms

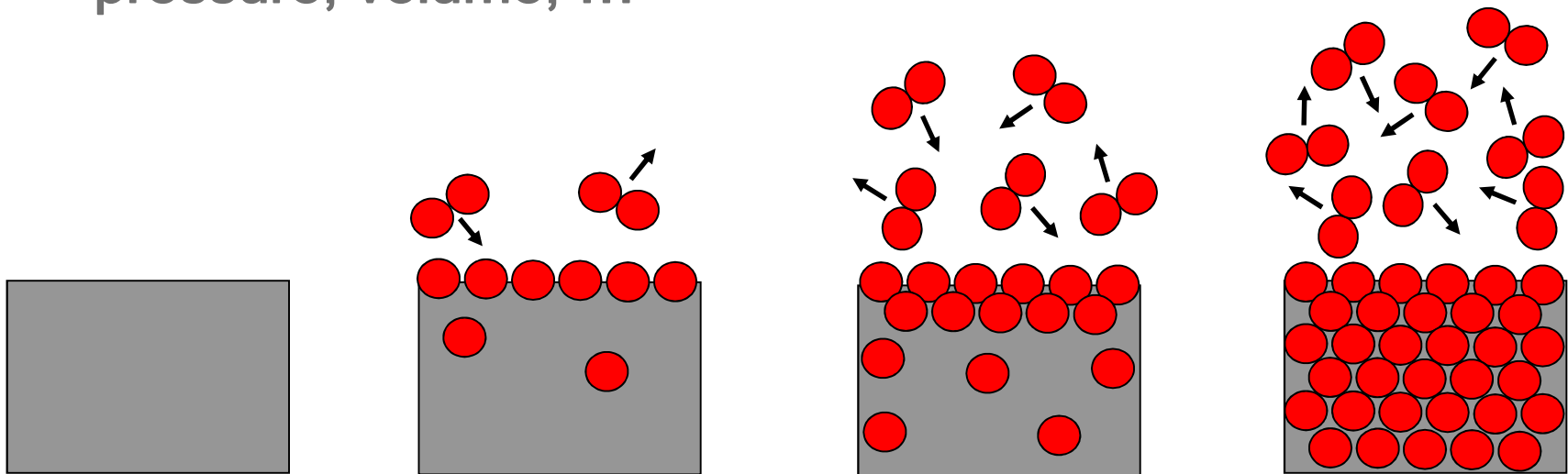
Adsorption will take place until the equilibrium is reached

Thermodynamics

□ Example

Consider a metal surface in an oxygen atmosphere

The point of equilibrium depends on temperature, pressure, volume, ...



Thermodynamics

□ Thermodynamic potentials

Internal energy $U(S, V, \{N\})$

Enthalpy $H(S, p, \{N\}) = U + pV$

Helmholtz free energy $F(T, V, \{N\}) = U - TS$

Gibbs free energy $G(T, p, \{N\}) = U - TS + pV$

Grand potential $\Omega(T, p, \{\mu\}) = U - TS - \sum_i N_i \mu_i$

Gibbs free energy 2 $G(T, p, \{N_{i \neq j}\}, \mu_j) = G - N_j \mu_j$

Energy balance equation

$$dU = TdS - pdV + \sum_i \mu_i dN_i$$

with chemical potentials

$$\mu_i = \left(\frac{\partial U}{\partial N_i} \right)_{S, V} = \left(\frac{\partial H}{\partial N_i} \right)_{S, p} = \left(\frac{\partial F}{\partial N_i} \right)_{T, V} = \left(\frac{\partial G}{\partial N_i} \right)_{T, p}$$

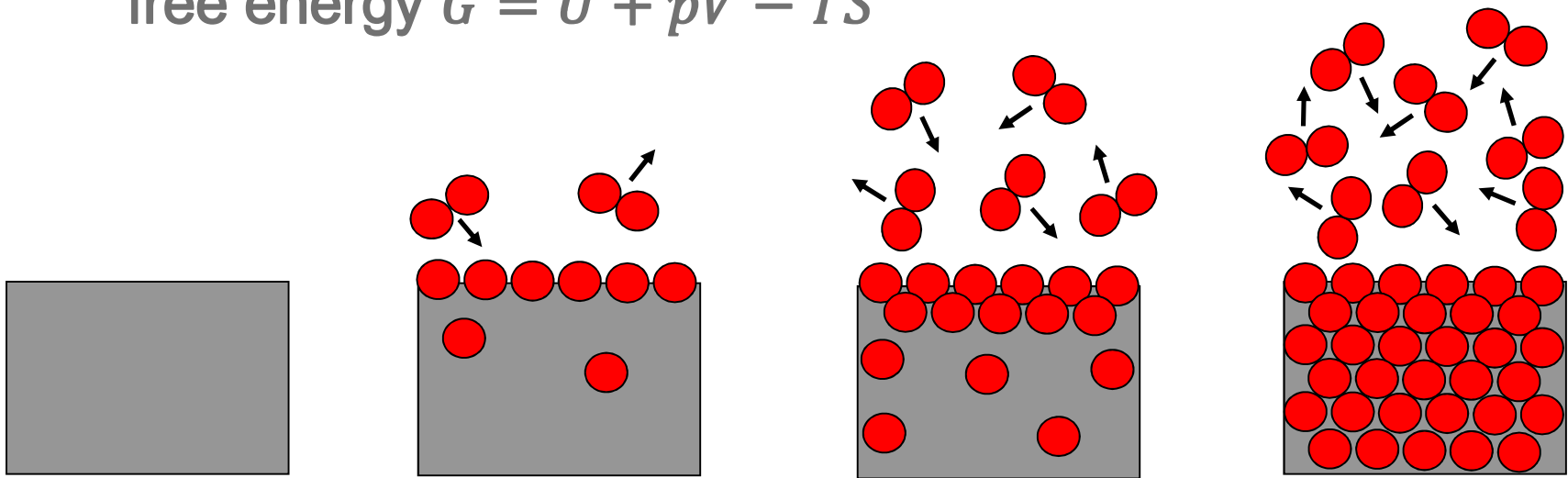
Thermodynamics

□ Reaching the equilibrium

At constant T a system minimizes its free energy ($-TS$), not the internal energy U

If also volume V is constant, the energy minimized is the Helmholtz free energy $F = U - TS$

If (T, p) are constant, the energy minimized is the Gibbs free energy $G = U + pV - TS$



Thermodynamics

□ Statistical thermodynamics



$$S = k \log W$$

W - number of *microstates* for a given *macrostate*

This is “only” a postulate - but it works!

Why it should work: (i) in equilibrium $W \rightarrow \max$, so that $S \rightarrow \max$; (ii) S is additive, but from probability laws W is multiplicative

Thermodynamics

□ Statistical thermodynamics

Let us consider a system that can be in one of states i with energy E_i

At a given T , the probability of the system to be in state i is $P_i = \frac{e^{-E_i/kT}}{Z}$, $Z = \sum_i e^{-E_i/kT}$, $\sum_i P_i = 1$

Ergodic hypothesis: average over time is equal to the average over ensemble - holds if all states are equiprobable (for most realistic systems)

What are the average values of entropy and thermodynamic potentials?

Thermodynamics

□ Statistical thermodynamics

Consider the ensemble of N replicas of the system - let us count microstates of this ensemble

A microstate describes which replicas are in which state, while a macrostate describes how many replicas are in each state; thus: $W = \frac{N!}{N_1!(N-N_1)!} \frac{(N-N_1)!}{N_2!(N-N_1-N_2)!} \dots = \frac{N!}{N_1!N_2!\dots}$ where N_1, N_2, \dots are the numbers of the replicas in state 1, 2, ...

$$N_i = NP_i = N \frac{e^{-E_i/kT}}{Z}, \quad \tilde{S} = k \ln W = k \ln(N!) - k \sum_i \ln(N_i!)$$

Z - canonical *partition function*

Use Stirling's formula: $\ln(N!) \approx N \ln N - N$

Thermodynamics

□ Statistical thermodynamics

$$\tilde{S} = k \ln W = Nk \ln Z + \frac{N}{TZ} \sum_i E_i e^{-E_i/kT}$$

Internal energy, by definition: $\tilde{U} = \frac{N}{Z} \sum_i E_i e^{-E_i/kT} = \frac{NkT^2}{Z} \frac{\partial Z}{\partial T}$

$$U = \frac{\tilde{U}}{N} = \frac{kT^2}{Z} \frac{\partial Z}{\partial T} = kT^2 \frac{\partial \ln Z}{\partial T}$$

$$S = \frac{\tilde{S}}{N} = \frac{k \ln W}{N} = k \ln Z + \frac{U}{T} = k \ln Z + kT \frac{\partial \ln Z}{\partial T}$$

$$F = U - TS = -kT \ln Z$$

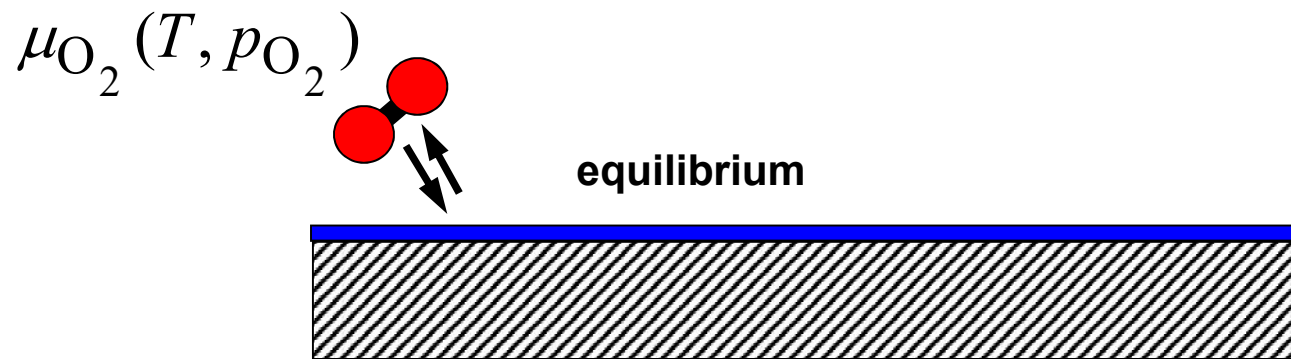
$$G = F + pV = -kT \ln Z + pV$$

$$\mu(T, p) = \left(\frac{\partial G}{\partial N} \right)_{T, p} = \frac{\partial}{\partial N} (-kT \ln Z + pV)_{T, p}$$

Thermodynamics

□ Statistical thermodynamics

Practical example: surface free energy



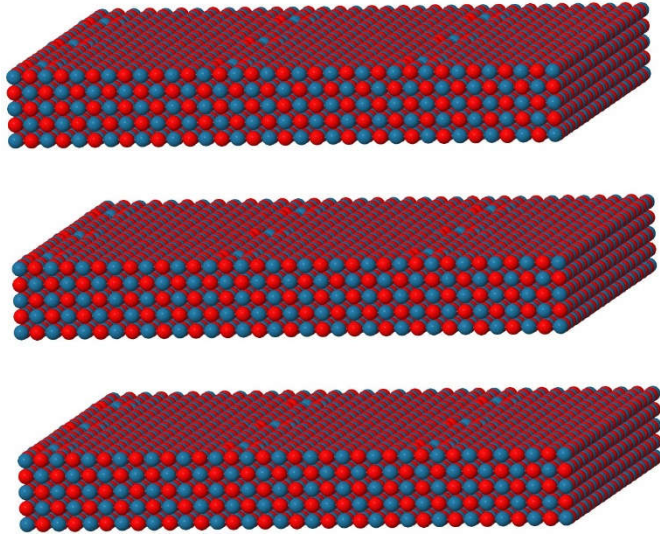
Change in Gibbs free energy upon addition of O to the surface: $\Delta G = G_{surf}(N_O + 1) - \left(G_{surf}(N_O) + \frac{1}{2} \mu_{O_2} \right)$

since $\mu_O = \frac{1}{2} \mu_{O_2}$

Goal - find surface composition that minimizes G at given T, p

Surface modeling

1) Slab model (supercell approach)

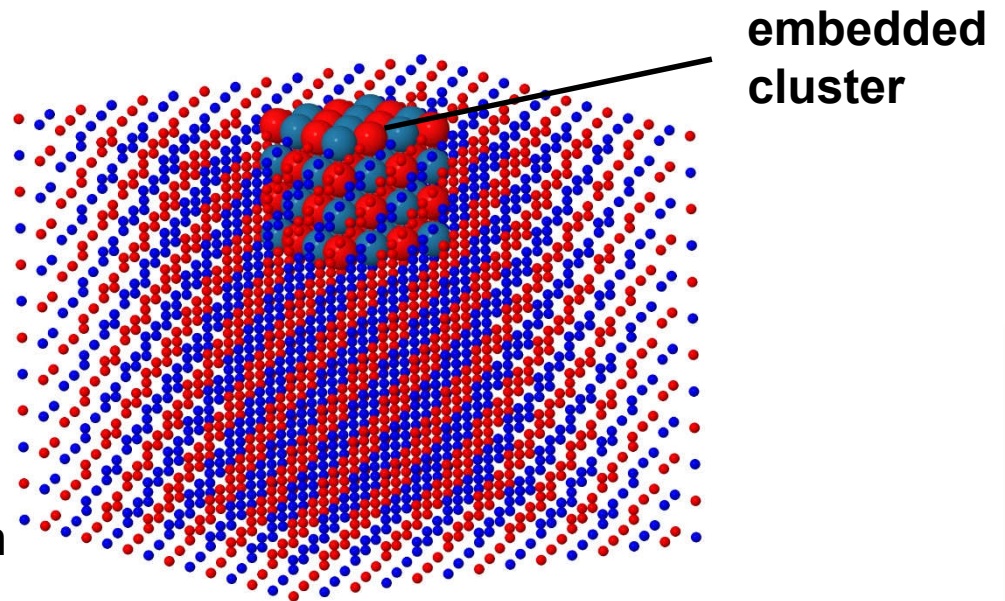


- + regular surfaces
- + coverage dependence
- ± defect-defect or adsorbate-adsorbate interaction

2) Cluster model:

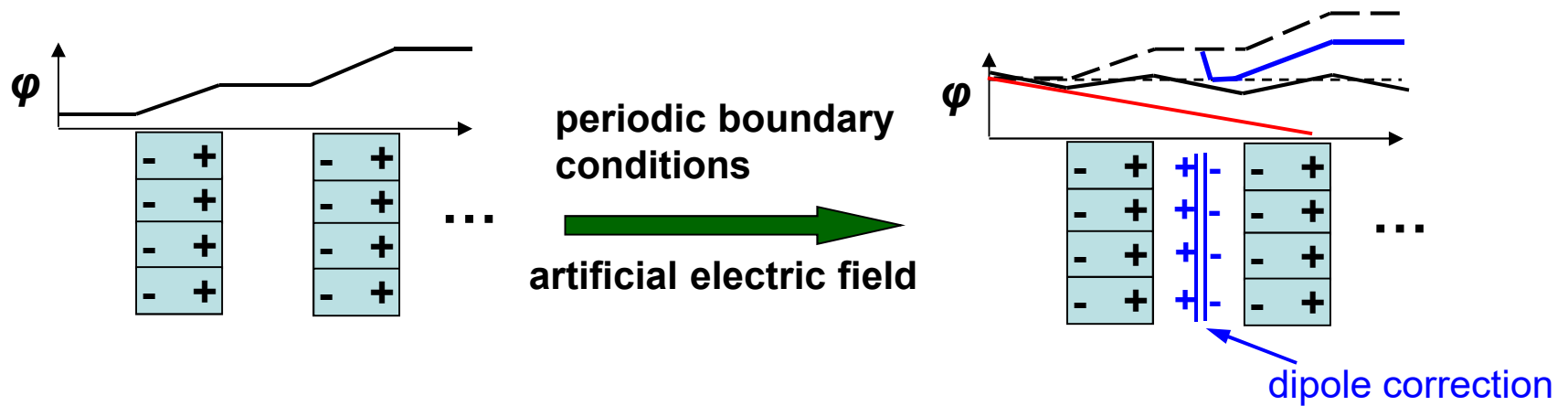
- + isolated defects or adsorbates
- border effects

Embedding: point charges (ionic systems), dangling bond saturation (covalently-bound systems),...

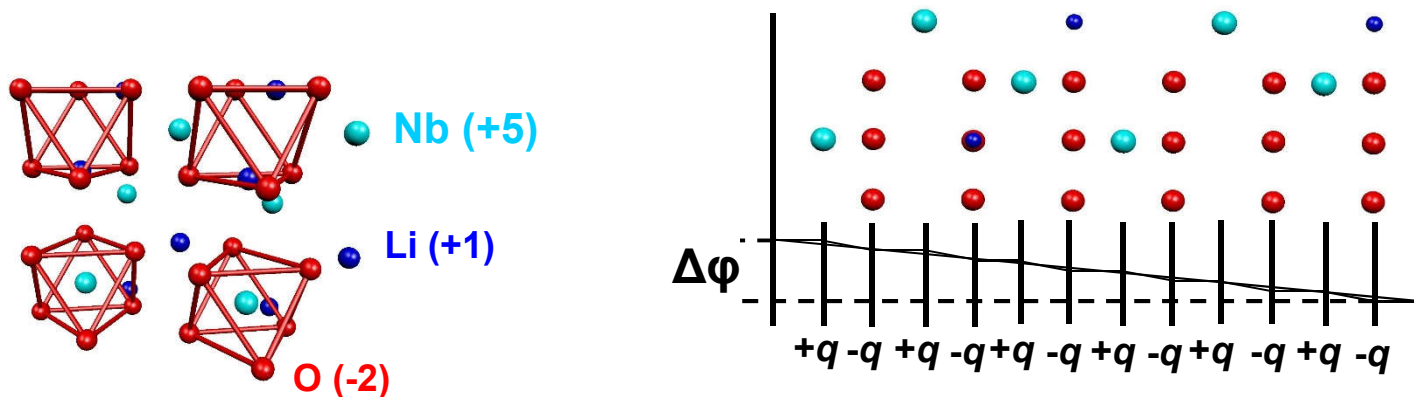


Surface modeling: important issues

- 1) Finite slab thickness (surface-surface interaction)
- 2) Finite vacuum layer thickness (image-image interactions)
- 3) Long-range interactions (charge, dipole moment)



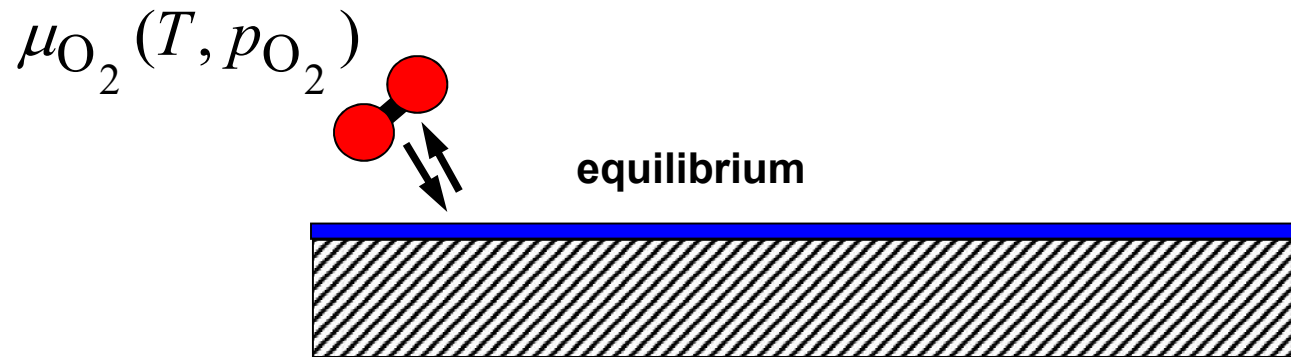
4) Surface polarity



Thermodynamics

□ Statistical thermodynamics

Practical example: surface free energy



Change in Gibbs free energy upon addition of O to the surface: $\Delta G = G_{surf}(N_O + 1) - \left(G_{surf}(N_O) + \frac{1}{2} \mu_{O_2} \right)$

since $\mu_O = \frac{1}{2} \mu_{O_2}$

Goal - find surface composition that minimizes G at given T, p

Thermodynamics

□ Statistical thermodynamics

Practical example: surface free energy

$$\Delta\gamma(N_O, T, p) = \frac{1}{A} [G_{surf}(N_O, T, p) - G_{surf}(N_O^{ref}, T, p) - \mu_O(N_O - N_O^{ref})] \rightarrow \min_{N_O}$$

where A is the surface area, N_O^{ref} is the number of O atoms in the reference system

$$G_{surf}(N_O) - G_{surf}(N_O^{ref}) = \Delta E_{surf} + \Delta U_{vib} - T\Delta S_{vib} - T\Delta S_{conf} + p\Delta V$$

$$\mu_O(T, p) - ?$$

In thermodynamic equilibrium, μ is the same everywhere (gas, surface, bulk) - can calculate μ in gas

Thermodynamics

- **Statistical thermodynamics**

Let us consider a gas of N non-interacting diatomic (for simplicity) molecules

Thermodynamics

□ Statistical thermodynamics

Let us consider a gas of N non-interacting diatomic (for simplicity) molecules

Each molecule has the following degrees of freedom: nuclear, electronic, *translational*, rotational, vibrational

$$Z = \frac{(z_{transl})^N}{N!} (z_{rot})^N (z_{vib})^N (z_{el})^N (z_{nucl})^N$$

translational states are invariant with respect to any permutations of molecules (indistinguishable molecules)

z_x - partition function for the degree of freedom x for a single molecule

Thermodynamics

□ Statistical thermodynamics

$$\mu(T, p) = \frac{\partial}{\partial N} (-NkT \ln(z_{transl}) + kT \ln N! - NkT \ln(z_{rot}) - NkT \ln(z_{vib}) - NkT \ln(z_{el}) - NkT \ln(z_{nucl}) + pV)_{T, p}$$

Remember ideal gas law $pV = NkT$ and Stirling's formula

$$\mu(T, p) = -kT \ln \left(\frac{z_{transl}}{N} \right) - kT \ln(z_{rot}) - kT \ln(z_{vib}) - kT \ln(z_{el}) - kT \ln(z_{nucl}) + kT$$

$$\frac{z_{transl}}{N} = \frac{V}{N} \int e^{-\frac{\hbar \mathbf{k}^2}{2mkT}} d\mathbf{k} = \frac{V}{N} \left(\frac{2\pi mkT}{\hbar^2} \right)^{\frac{3}{2}} = \frac{kT}{p} \left(\frac{2\pi mkT}{\hbar^2} \right)^{\frac{3}{2}}$$

required input - molecule's mass m

$$z_{el} = \sum_i (2s_i + 1) e^{-\frac{E_i}{kT}} \approx (2s_0 + 1) e^{-\frac{E_0}{kT}} \rightarrow \mu_{el} \approx E_0 - kT \ln(2s_0 + 1)$$

required input - E_0, S

Thermodynamics

□ Statistical thermodynamics

$$z_{rot} = \frac{1}{\sigma} \sum_J (2J + 1) e^{-\frac{B_0 J(J+1)}{kT}} \approx \frac{1}{\sigma} \int_0^{\infty} (2J + 1) e^{-\frac{B_0 J(J+1)}{kT}} dJ = \frac{T}{\sigma \theta_r}$$

where $\sigma = 2$ for homonuclear molecules (indistinguishable with respect to permutation of the two identical nuclei), $\sigma = 1$ for heteronuclear molecules,

$$\theta_r = \frac{\hbar^2}{2kI}, \quad I = \frac{m_A m_B}{m_A + m_B} d^2, \quad d \text{ is the bond length}$$

$\mu_{rot} \approx -kT \ln \left(\frac{2kTI}{\sigma \hbar^2} \right)$, required input - rotational constant
(calculated or from microwave spectroscopy)

Thermodynamics

□ Statistical thermodynamics

$$Z_{vib} = \prod_{i=1}^M \sum_{n=0}^{\infty} e^{-\left(n+\frac{1}{2}\right)\frac{\hbar\omega_i}{kT}} = \prod_{i=1}^M e^{-\frac{\hbar\omega_i}{2kT}} \sum_{n=1}^{\infty} e^{-\frac{n\hbar\omega_i}{kT}} =$$
$$= \prod_{i=1}^M \frac{e^{-\frac{\hbar\omega_i}{2kT}}}{1 - e^{-\frac{\hbar\omega_i}{kT}}} \text{ (used the fact that sum over } n \text{ is a geometric series)}$$

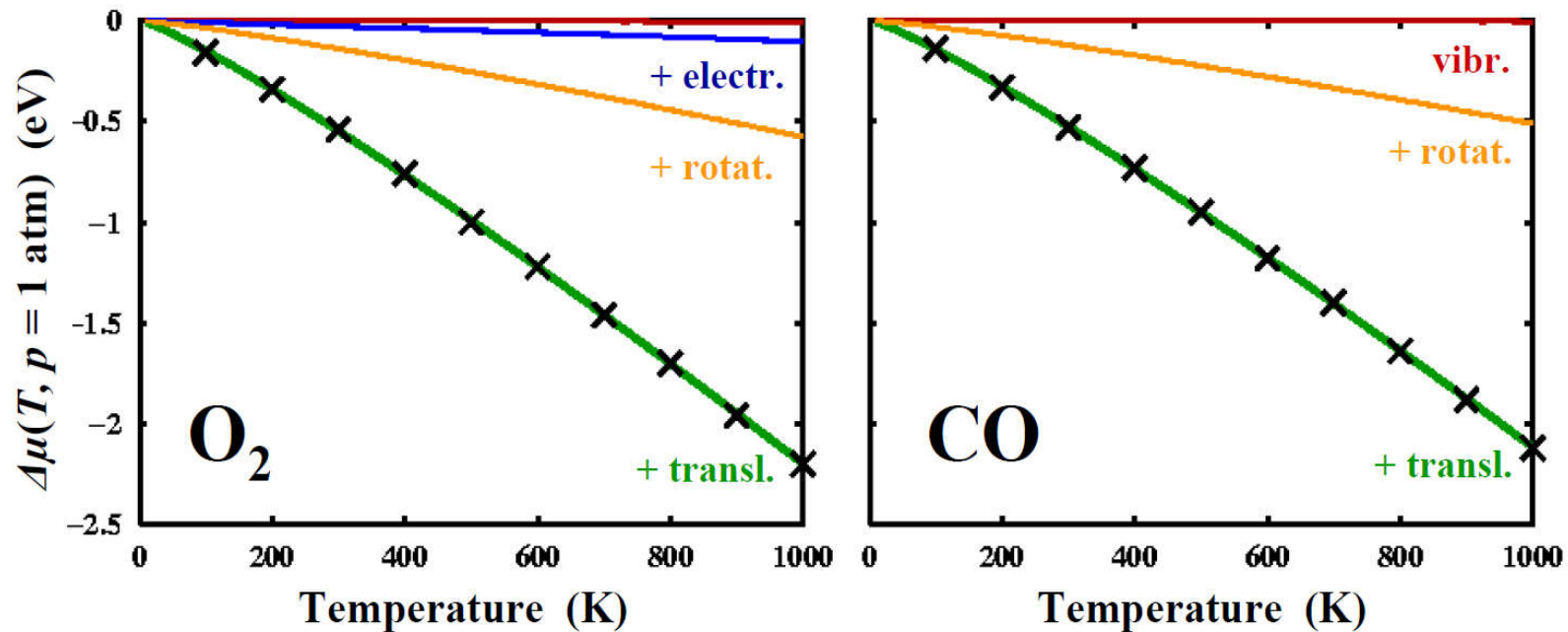
For a diatomic molecule $\mu_{vib} = \frac{\hbar\omega}{2} + kT \ln(1 - e^{-\hbar\omega/kT})$
required input - vibrational frequency ω

In most practical cases, we can neglect the interaction between nuclear spins, so that $Z_{nucl} \approx 1$ (not correct at very low temperatures)

Thermodynamics

□ Ab initio atomistic thermodynamics

It is convenient to define a reference for $\mu(T, p)$: $\mu(T, p) = E_0 + \Delta\mu(T, p)$

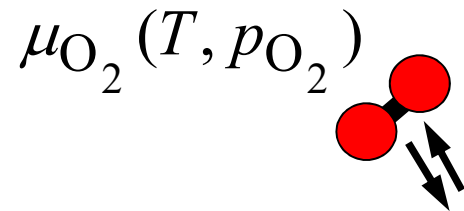


Alternatively: $\Delta\mu(T, p) = \Delta\mu(T, p^0) + k_B T \ln(p / p^0)$

and $\Delta\mu(T, p^0 = 1 \text{ atm})$ from thermochemical tables (e.g., JANAF)

Thermodynamics

□ *Ab initio* atomistic thermodynamics



$$\Delta\gamma(N_O, T, p) = \frac{1}{A} [\Delta E_{surf} + \Delta U_{vib} - T\Delta S_{vib} - T\Delta S_{conf} + p\Delta V - \mu_O\Delta N_O]$$

electronic structure calculations

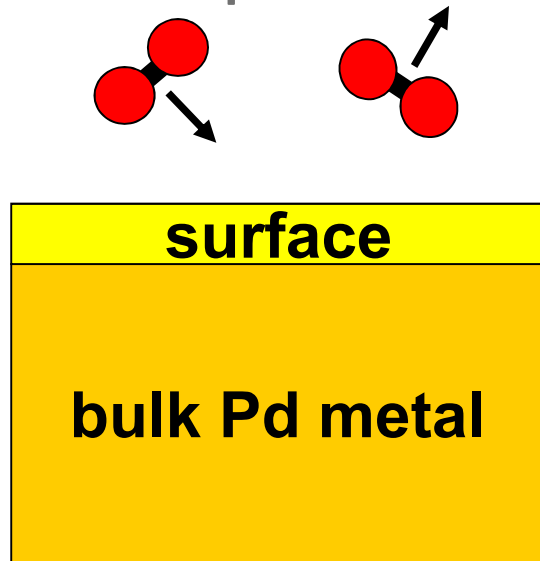
$$\Delta F_{vib}(T, V) = V \int_0^\infty f(T, \omega) (\sigma(\omega) - \sigma_{ref}(\omega)) d\omega, \sigma(\omega) -$$

phonon density of states, $f(T, \omega) = \frac{\hbar\omega}{2} + kT \ln(1 - e^{-\hbar\omega/kT})$

Thermodynamics

□ *Ab initio* atomistic thermodynamics

Example: Metal surface in contact with O₂ gas



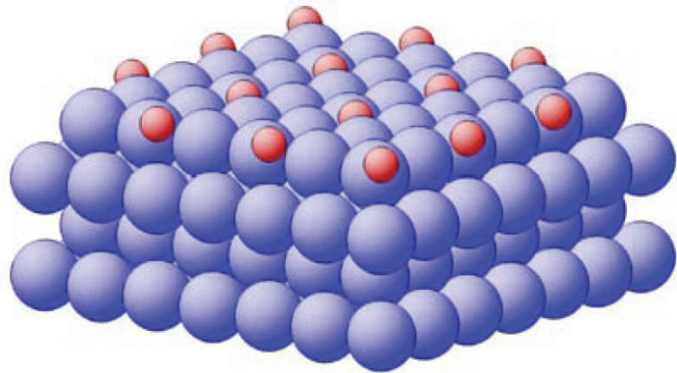
Reservoir: $\mu_O(T, p_{O_2})$ from ideal gas, $N_O^{ref} = 0$ (bare metal surface is the reference system), $\frac{1}{2}E_{O_2}$ is the reference for the chemical potential of O: $\mu_O = \Delta\mu_O + \frac{1}{2}E_{O_2}$

Neglect for now ΔF_{vib} and $T\Delta S_{conf}$

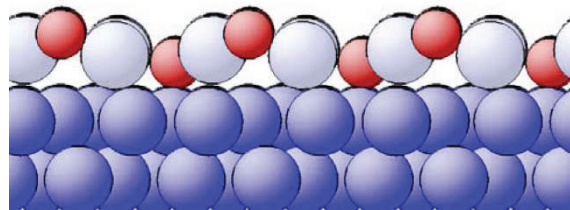
$$\Delta\gamma(T, p_{O_2}) = \frac{1}{A} \left[E_{surf}(N_O) - E_{surf}(0) - N_O \frac{1}{2} E_{O_2} \right] - \frac{1}{A} N_O \Delta\mu_O(T, p_{O_2})$$

Example: Pd(100)

$$\Delta\gamma(T, p_{O_2}) = \frac{1}{A} \Delta E_{surf}(N_O) - \frac{1}{A} N_O \Delta\mu_O(T, p_{O_2})$$

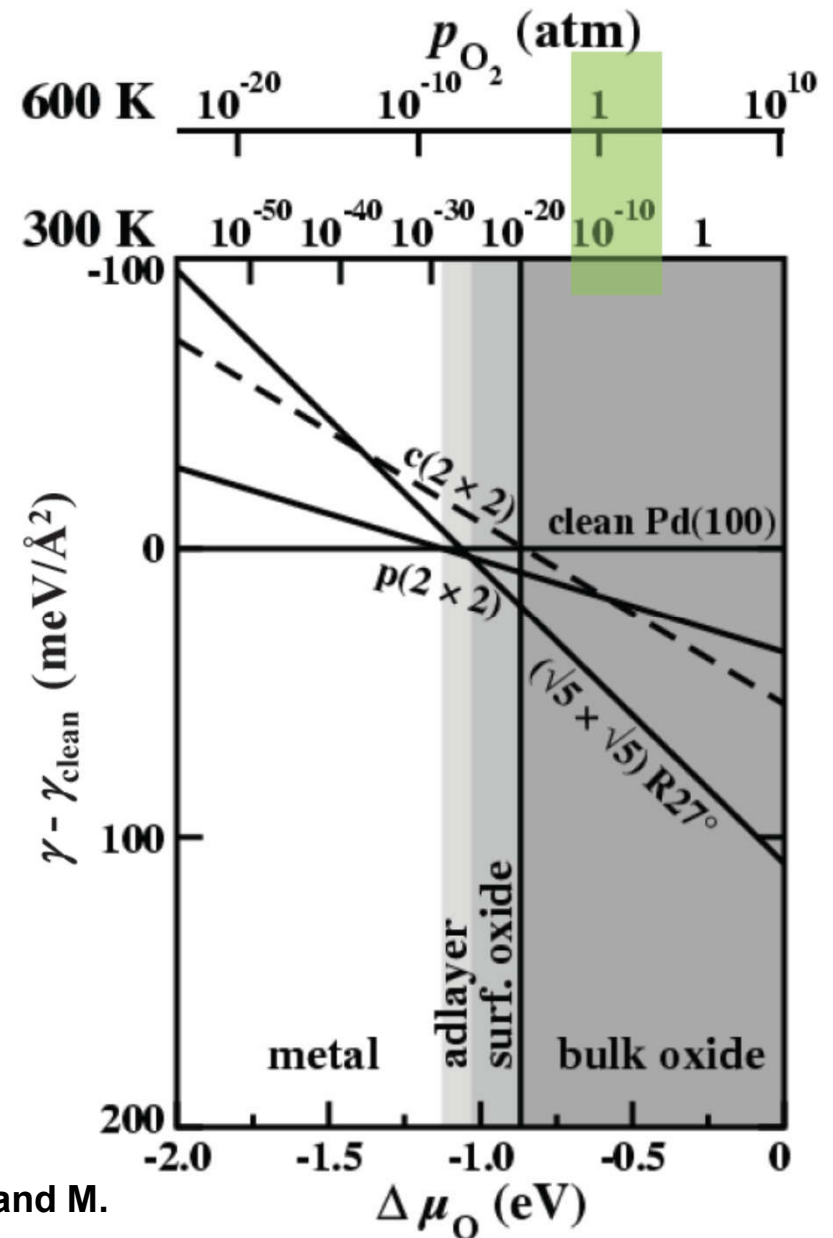


p(2x2) O/Pd(100)



($\sqrt{5} \times \sqrt{5}$)R27° PdO(101)/Pd(100)

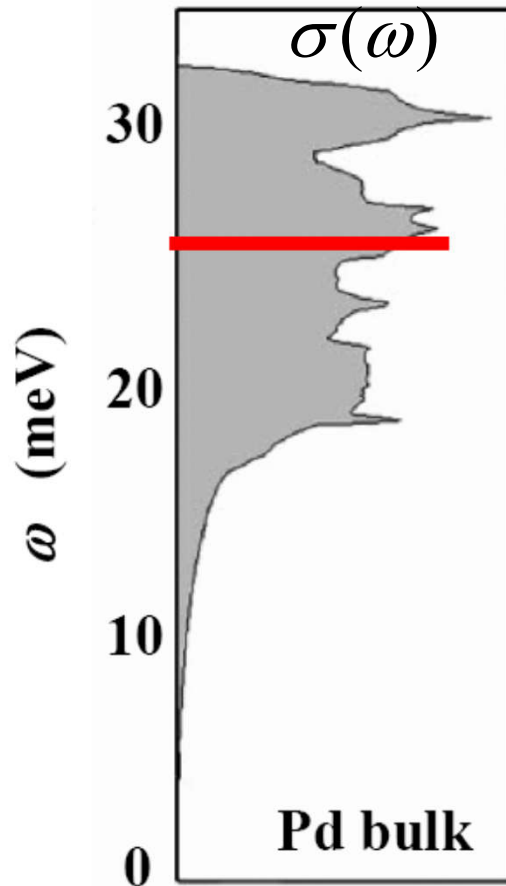
M. Todorova et al., Surf. Sci. 541, 101 (2003); K. Reuter and M. Scheffler, Appl. Phys. A 78, 793 (2004)



Thermodynamics

□ *Ab initio* atomistic thermodynamics

Vibrational contributions to the surface free energy:



$$\Delta F_{vib}(T, V) = V \int_0^{\infty} f(T, \omega) \left(\sigma(\omega) - \sigma_{ref}(\omega) \right) d\omega, \quad \sigma(\omega) - \text{phonon density of states, } f(T, \omega) = \frac{\hbar\omega}{2} + kT \ln(1 - e^{-\hbar\omega/kT})$$

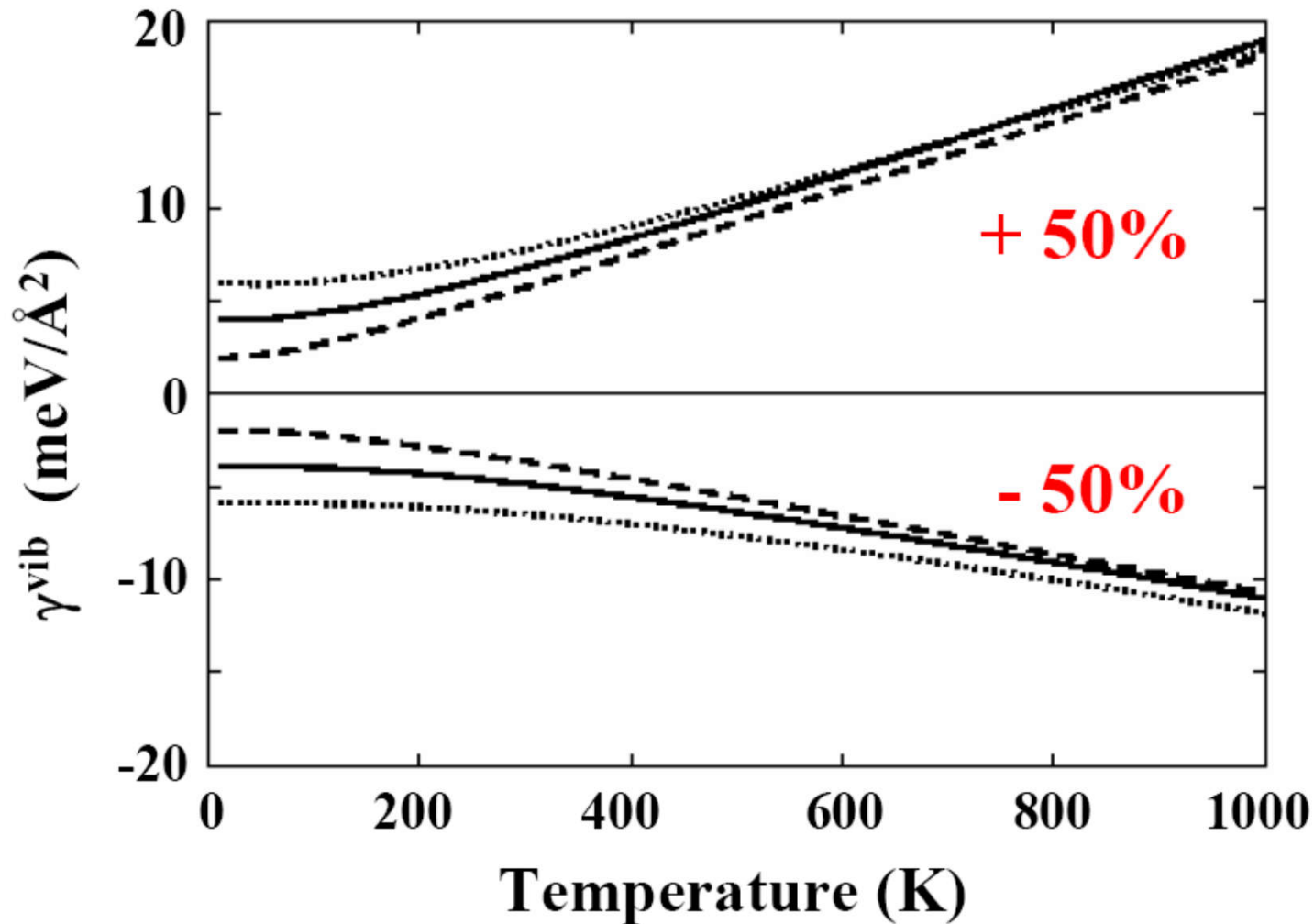
Only changes in vibrational free energy contribute to the surface free energy

Make estimate from simple models

e.g., Einstein model: $\sigma(\omega) = \delta(\omega - \langle \omega \rangle)$

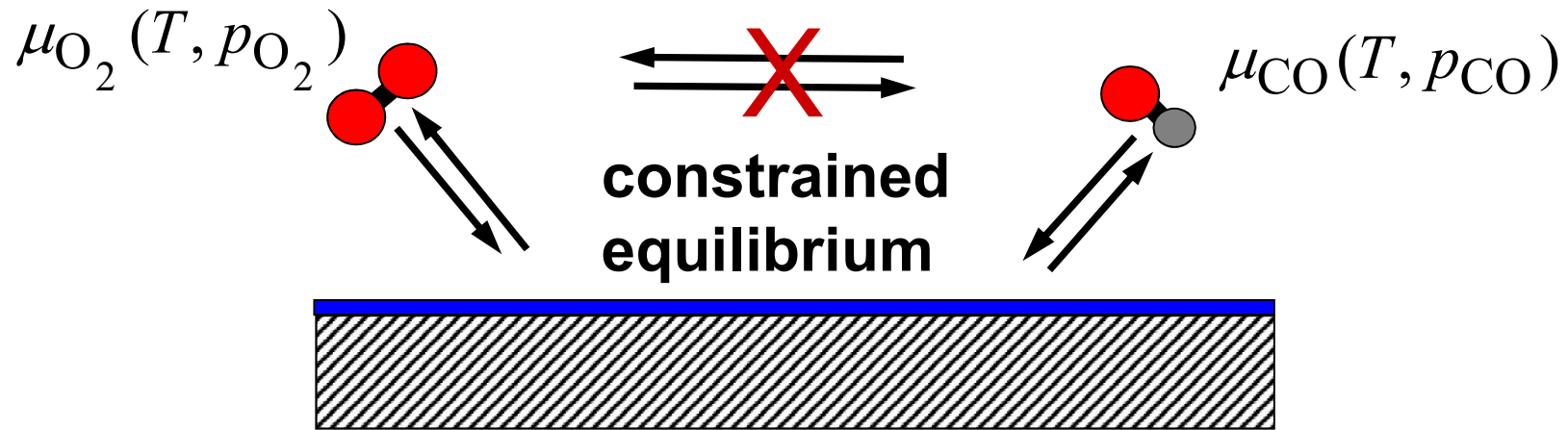
$$\langle \omega \rangle_{Pd}(\text{bulk}) \sim 25 \text{ meV}$$

Surface-induced variations of substrate modes



< 10 $\text{meV}/\text{\AA}^2$ for $T = 600$ K – in this case!!!

First-principles atomistic thermodynamics: constrained equilibria



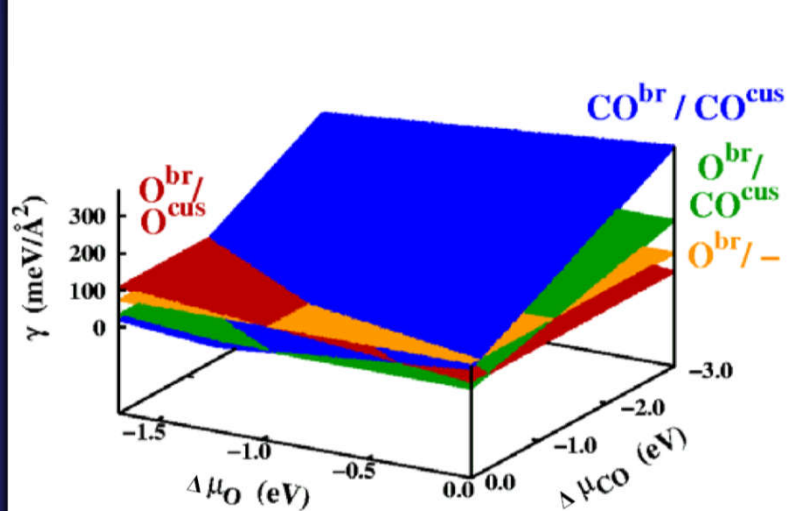
$$\Delta\gamma(T, p_{O_2}) = \frac{1}{A} \left[E_{surf}(N_O, N_{CO}) - E_{surf}^{ref} - N_O \frac{1}{2} E_{O_2} - N_{CO} E_{CO} \right]$$

$$- \frac{1}{A} N_O \Delta\mu_O(T, p_{O_2}) - \frac{1}{A} N_{CO} \Delta\mu_{CO}(T, p_{CO})$$

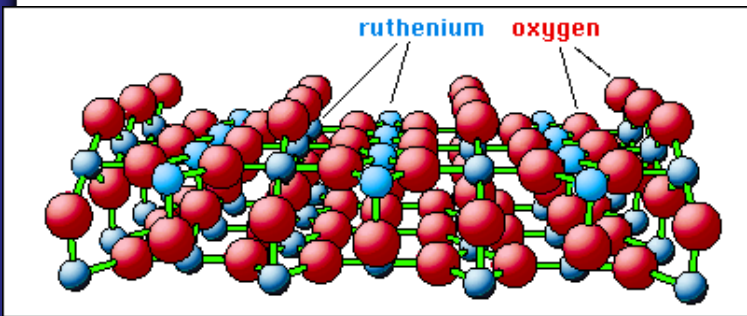
C.M. Weinert and M. Scheffler, *Mater. Sci. Forum* 10-12, 25 (1986); E. Kaxiras *et al.*, *Phys. Rev. B* 35, 9625 (1987);

K. Reuter and M. Scheffler, *Phys. Rev. B* 65, 035406 (2001); *Phys. Rev. B* 68, 045407 (2003)

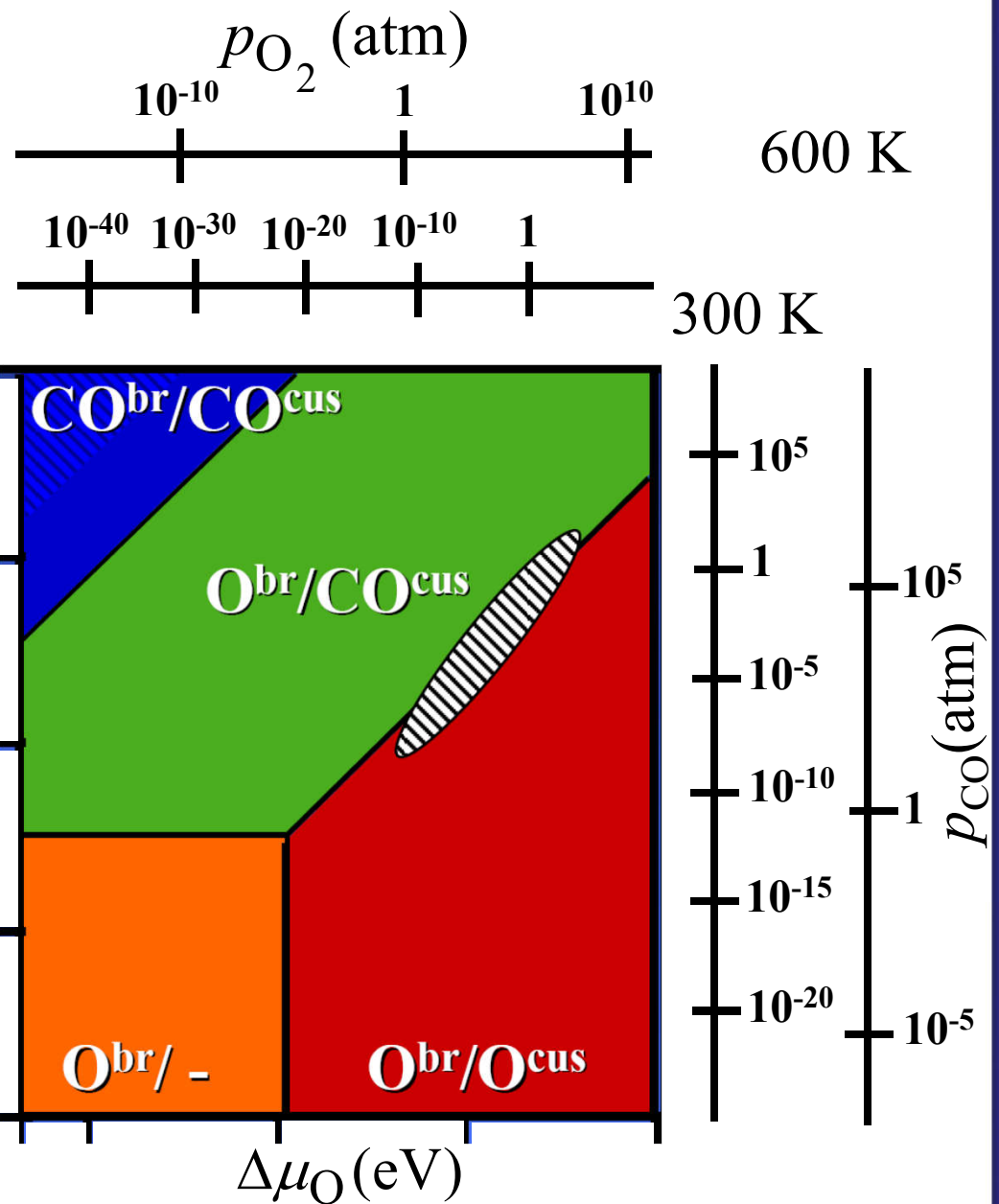
Surface phase diagrams



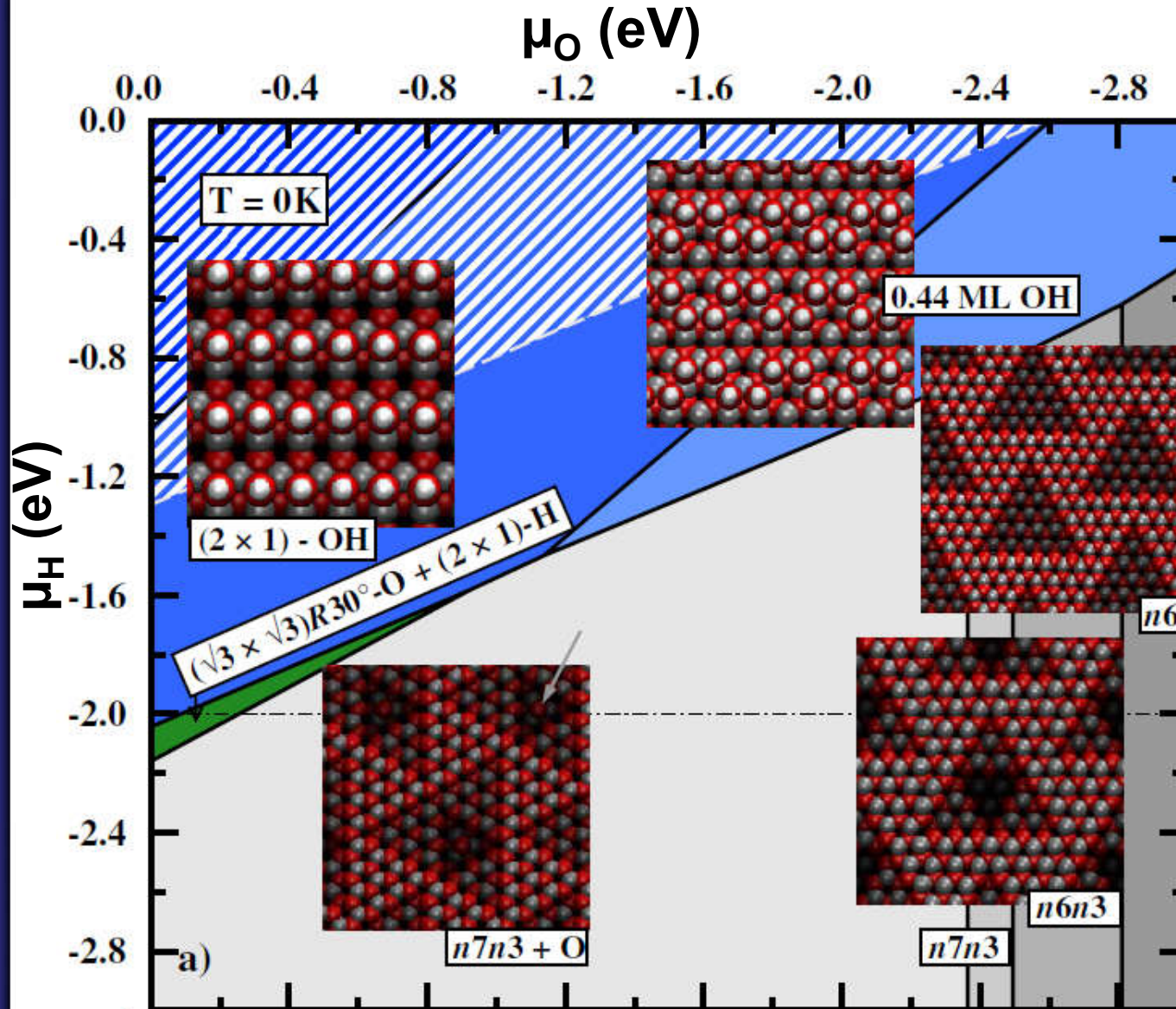
CO oxidation on RuO₂(110)



K. Reuter and M. Scheffler,
Phys. Rev. Lett. 90, 046103 (2003)



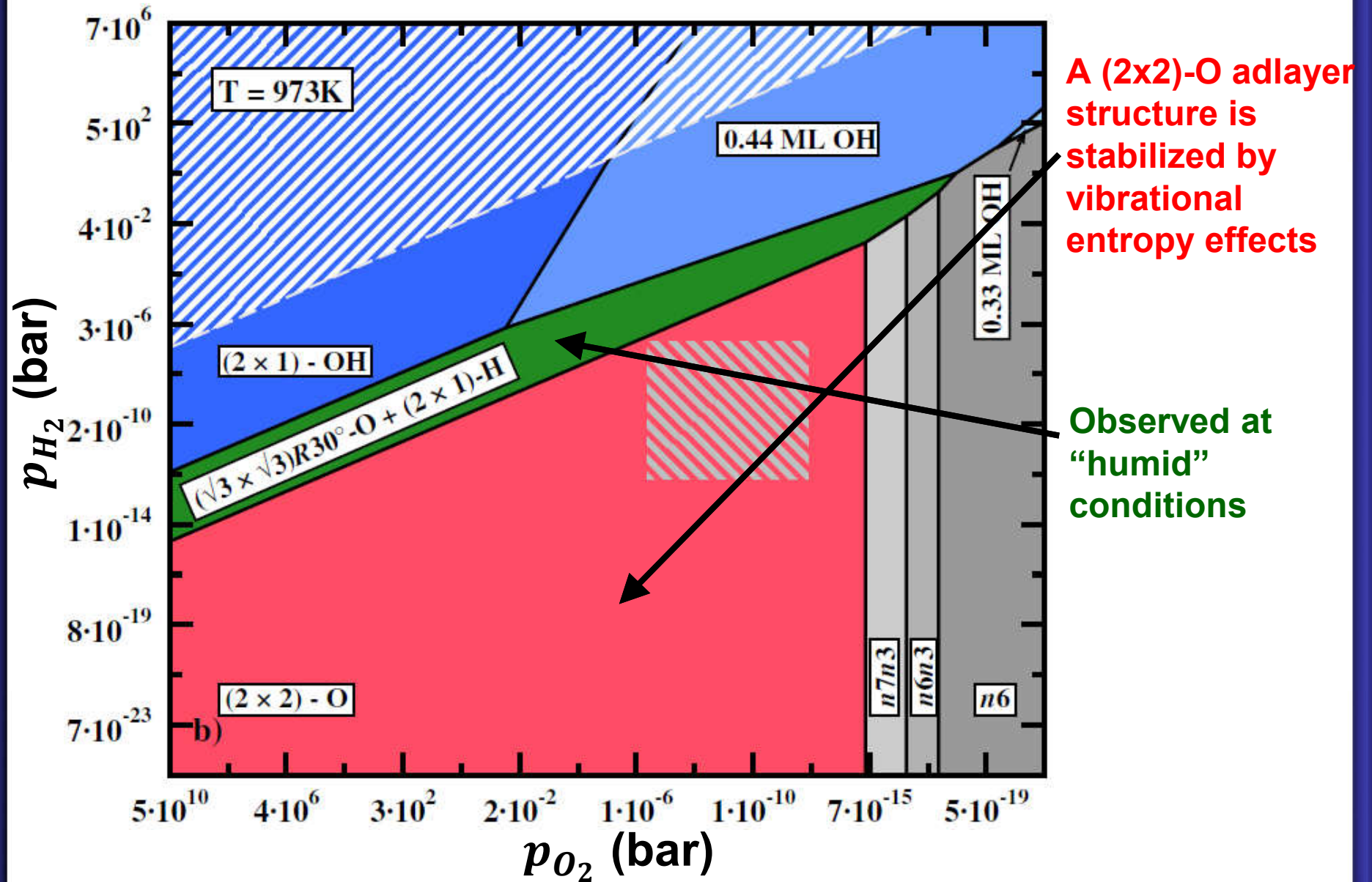
When vibrations do matter



ZnO (0001)
 surface phase
 diagram in $\text{H}_2\text{O}-\text{O}_2$
 atmosphere – no
 vibrations

No structure with
 (2×2)
 periodicity as seen
 at the ZnO(0001)
 surface
 annealed in a dry
 oxygen
 atmosphere
 (containing at
 maximum
 2 ppm water)

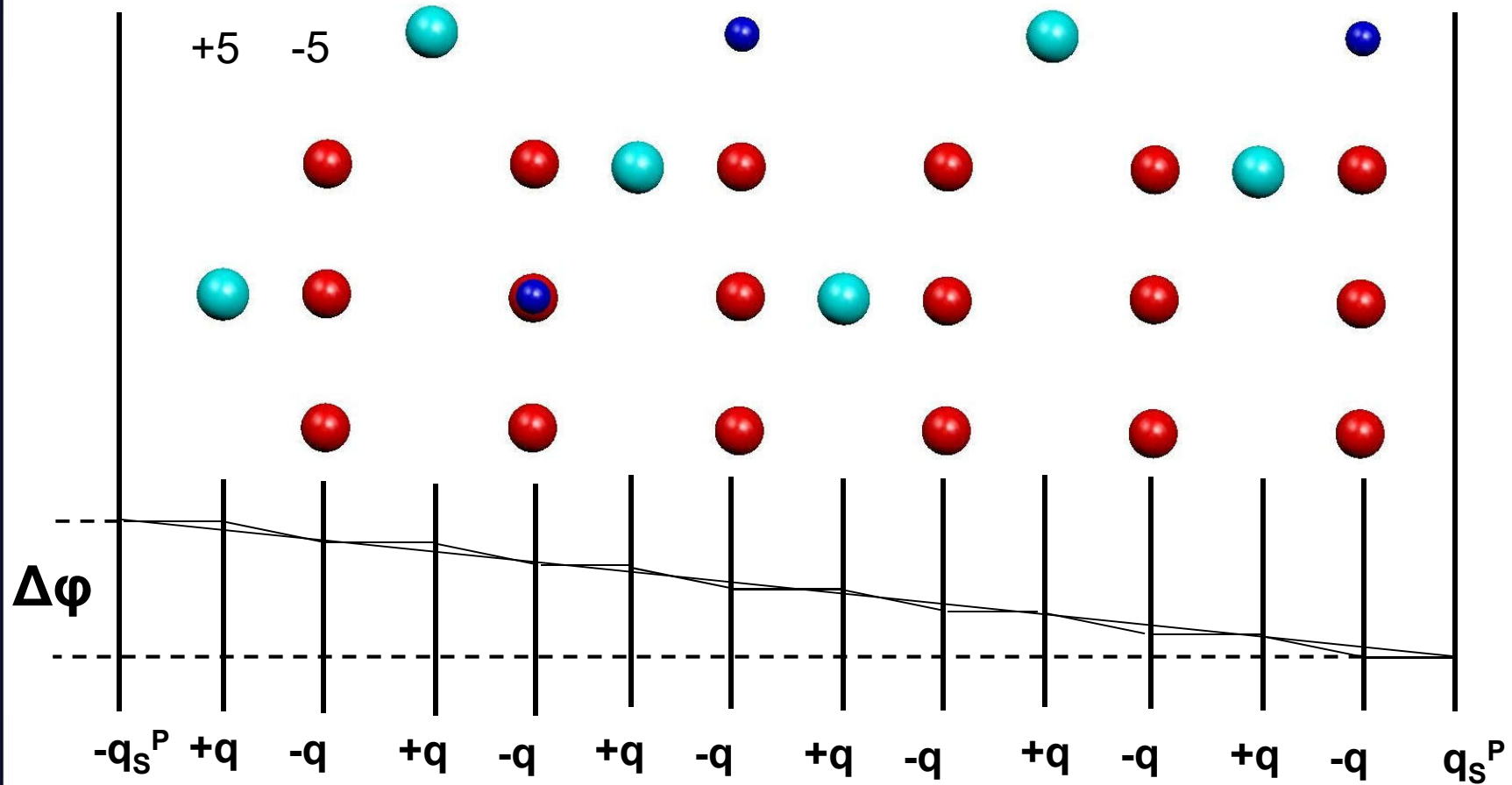
When vibrations do matter



M. Valtiner, M. Todorova, G. Grundmeier, and J. Neugebauer, PRL **103**, 065502 (2009)

Polar surfaces

Paraelectric lithium niobate (LiNbO_3) stoichiometric surfaces:

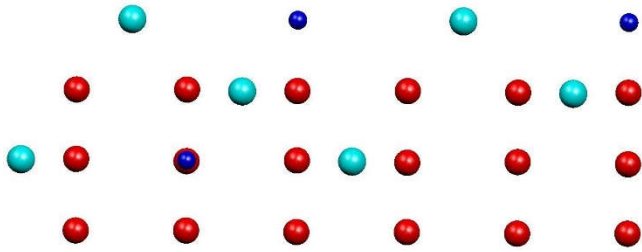


$$q_s^P = -q/2 \approx -2.5e \neq 0 \text{ – surface charge, } P_{PE} \neq 0$$

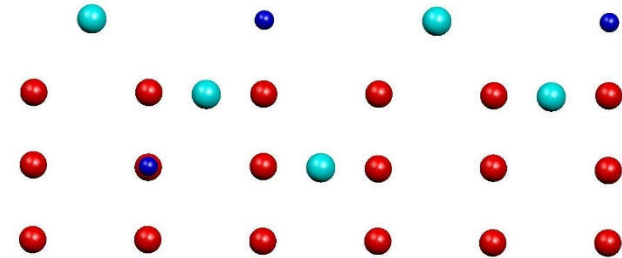
$\Delta\phi \approx 250 \text{ V} \gg E_g/e \approx 3.7 \text{ V} \rightarrow$ surface charge almost completely passivated

Polar surfaces

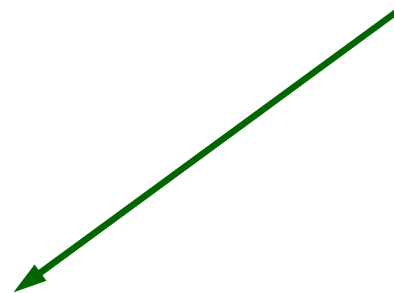
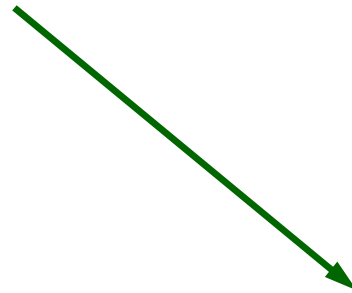
Where to cut?



Charge = 0,
Dipole moment $\neq 0$



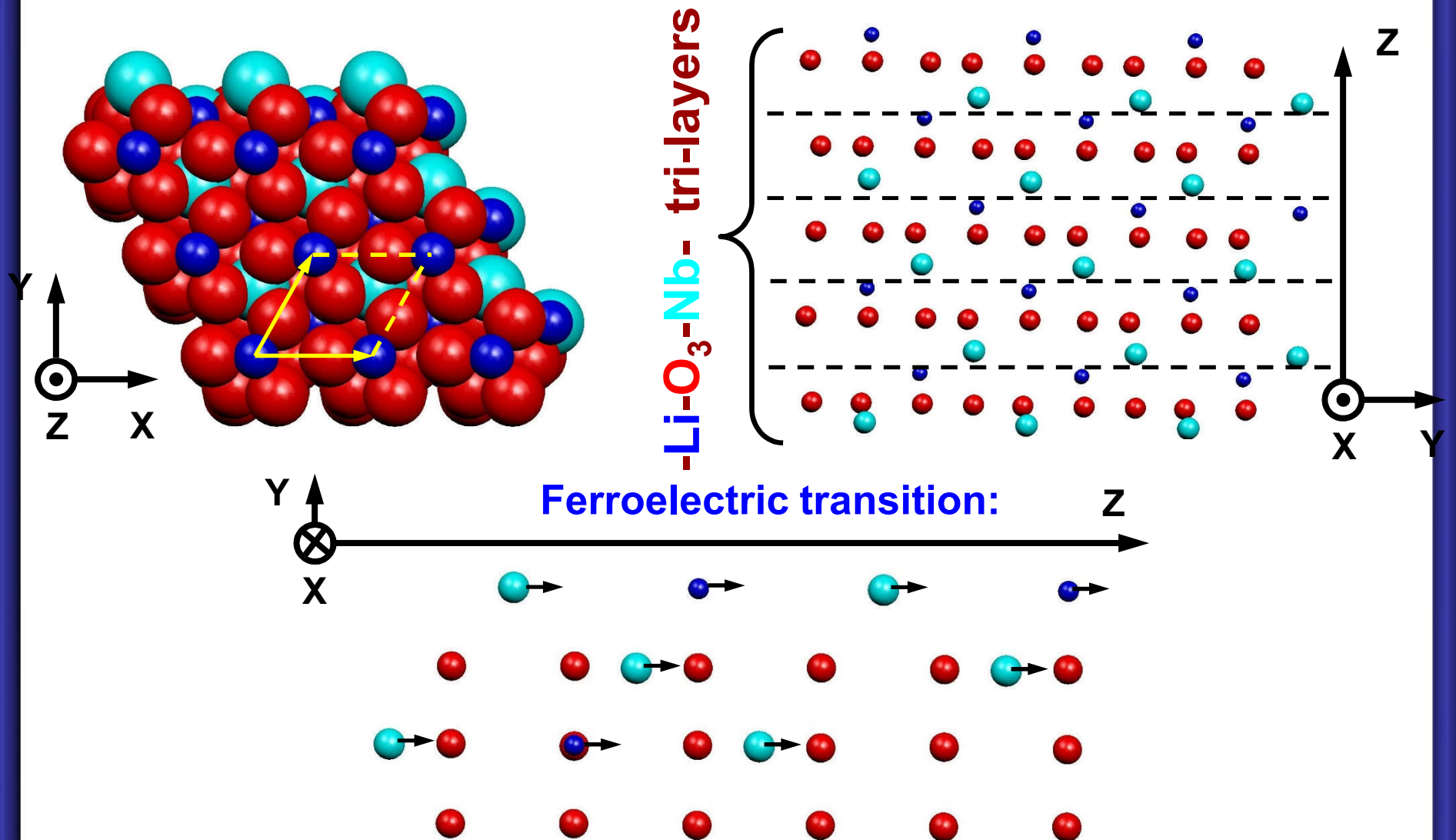
Charge = $-5e$,
Dipole moment = 0



Surface charge = $\pm 2.5e$

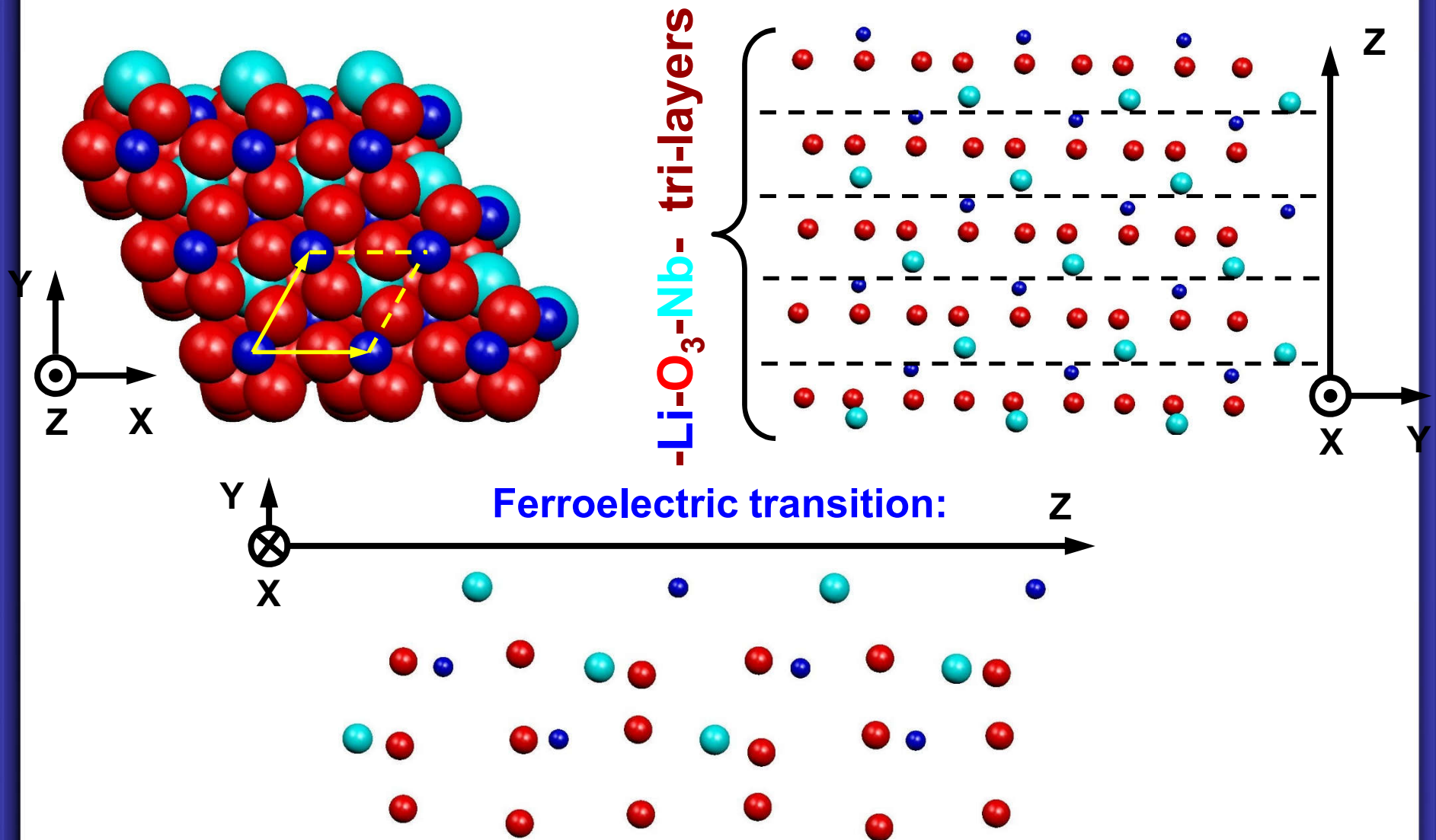
Ferroelectric lithium niobate LiNbO_3 .

Unrelaxed stoichiometric surface and layer stacking:

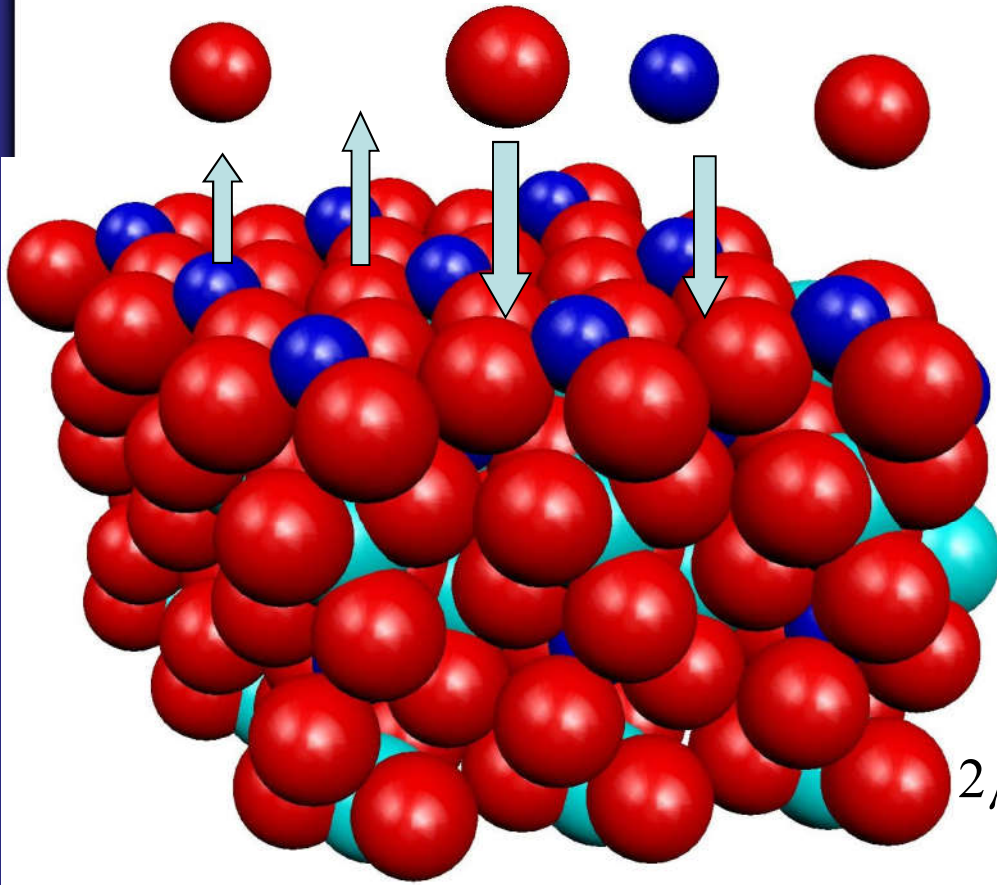


Ferroelectric lithium niobate LiNbO_3

Unrelaxed stoichiometric surface and layer stacking:



Surface and environment.



Chemical potentials μ_{Li} , μ_O , and μ_{Nb} such that:

1) bulk LN is stable:

$$\mu_{Li} + \mu_{Nb} + 3\mu_O = g_{LN}^{bulk}$$

2) no other condensed phases are stable:

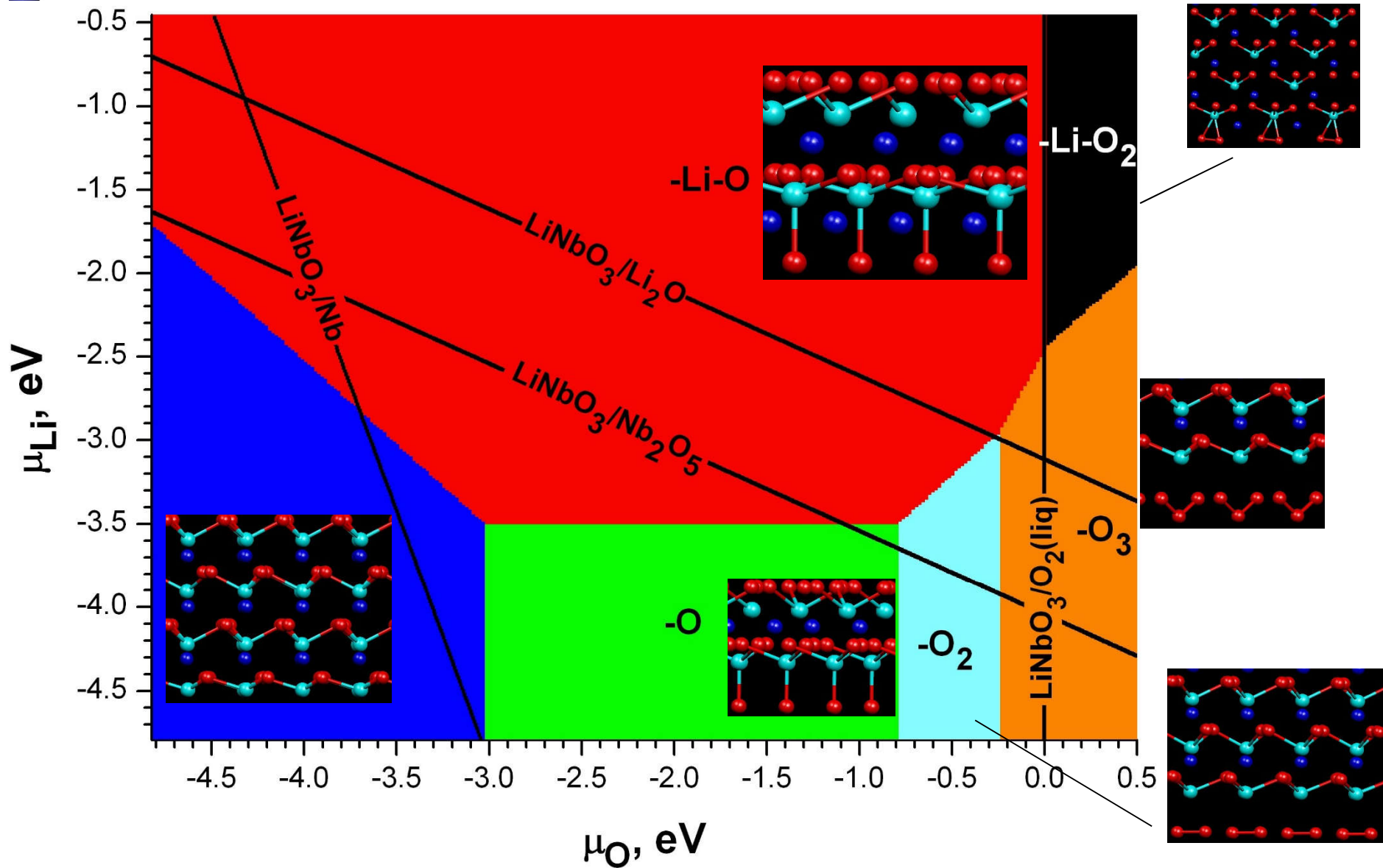
$$2\mu_{Li} + \mu_O < g_{Li_2O}^{bulk}, \quad 2\mu_{Nb} + 5\mu_O < g_{Nb_2O_5}^{bulk}$$

$$\mu_O < \mu_O^{\max} \approx \frac{1}{2} g_{O_2}, \quad \mu_{Li} < \mu_{Li}^{\max} \approx g_{Li}^{bulk}, \quad \mu_{Nb} < \mu_{Nb}^{\max} \approx g_{Nb}^{bulk}$$

Surface free energy:

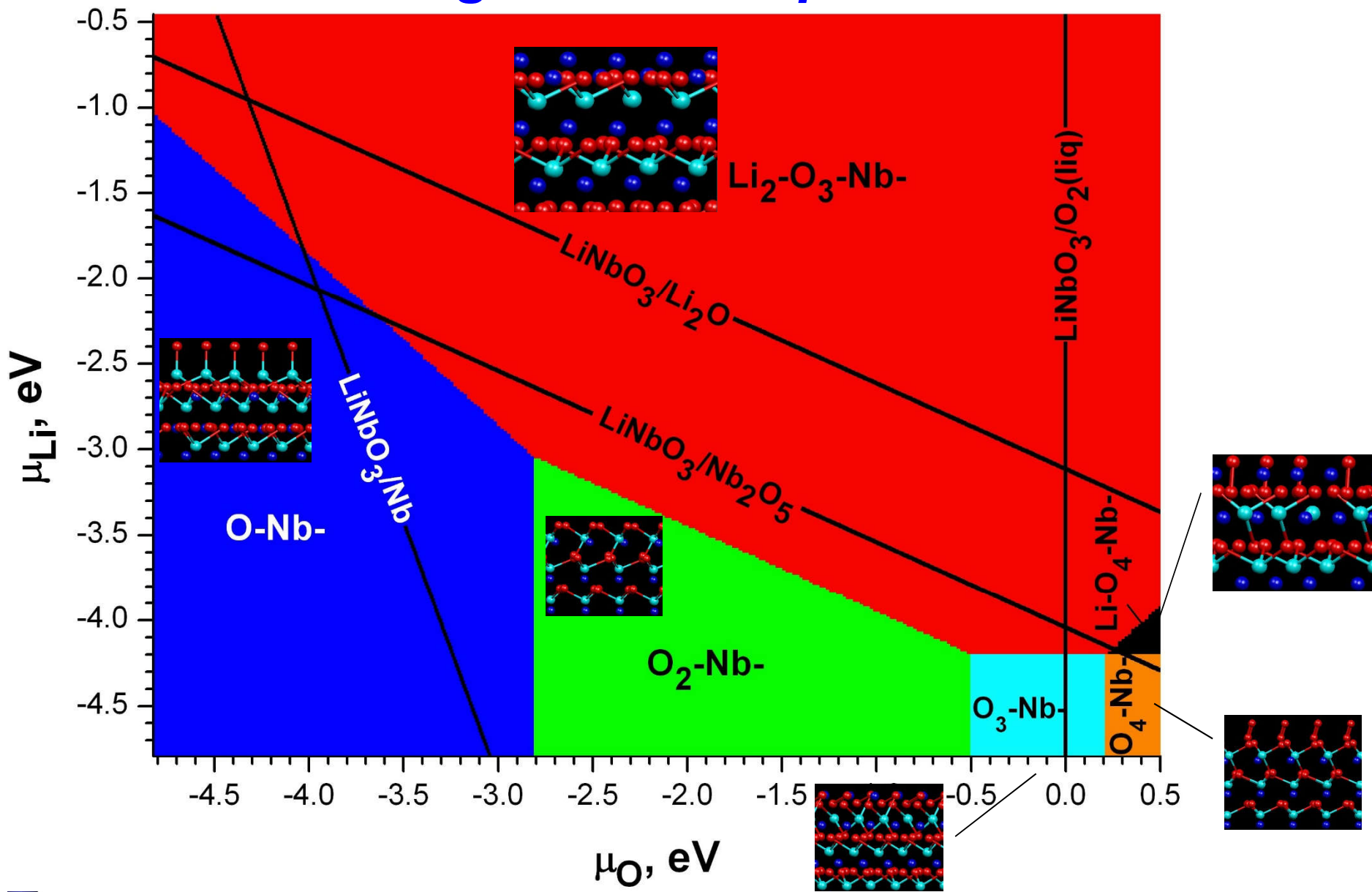
$$\gamma(T, p) = G^{slab}(N_{Nb}, N_{Li}, N_O) - \mu_{Nb}(T, p)N_{Nb} - \mu_{Li}(T, p)N_{Li} - \mu_O(T, p)N_O$$

Phase diagram for the *negative* surface



Levchenko, Rappe, PRL 100, 256101 (2008)

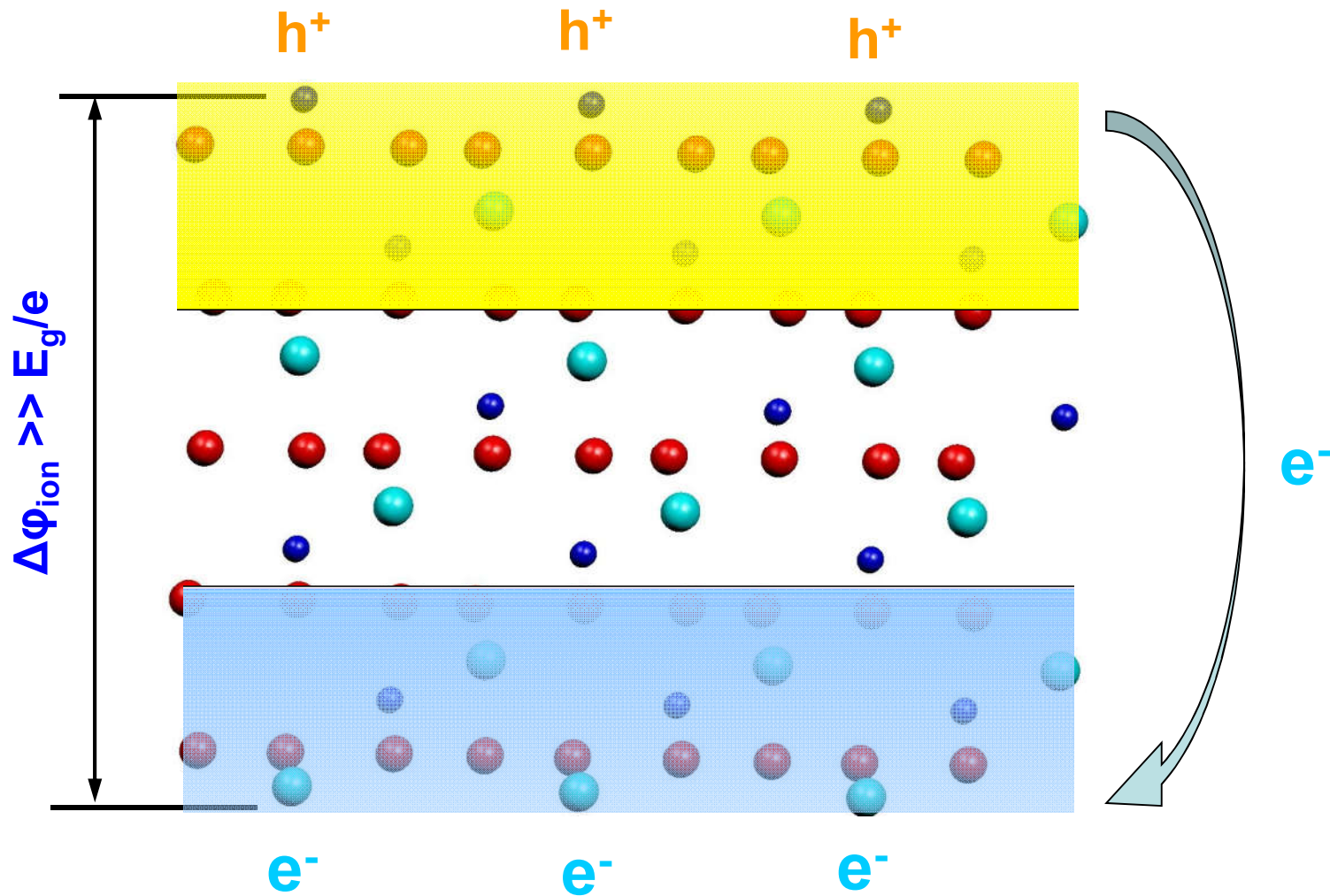
Phase diagram for the *positive* surface



Levchenko, Rappe, PRL 100, 256101 (2008)

Surface charge passivation

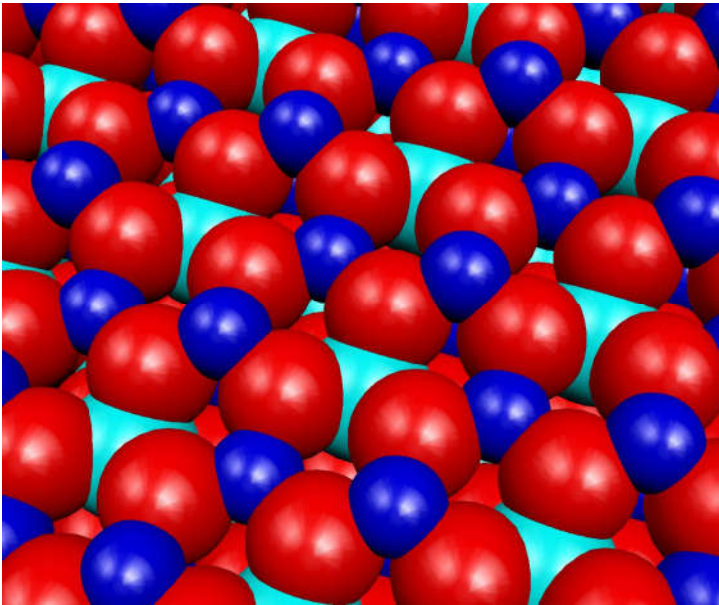
Fixed stoichiometry: surface charge passivated by **electrons** and **holes**.



About $1e^-/\text{unit cell}$ is transferred

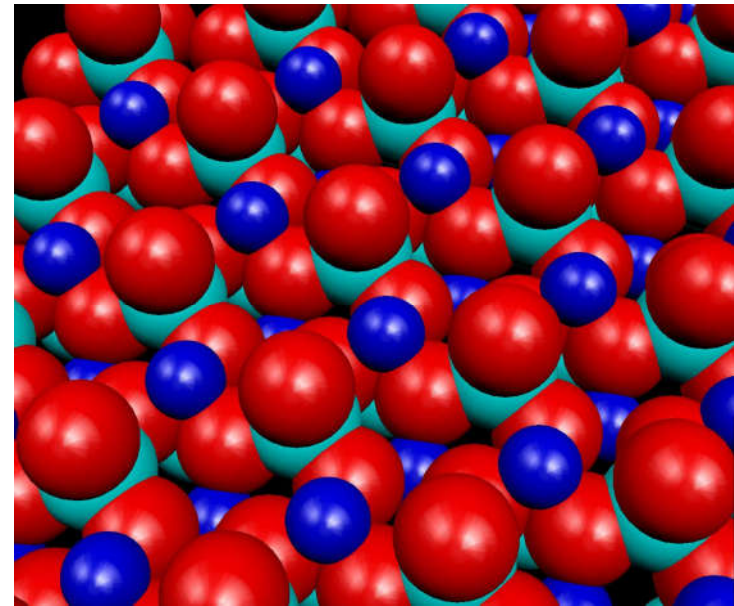
Most stable terminations: explanation

positive surface:



Accommodates compensating h^+ : additional Li stabilizes h^+ by forming Li^+

negative surface:



Accommodates compensating e^- : additional LiO stabilizes e^- by forming LiO^-

Compensation with ions is preferred over compensation with mobile charges!

Levchenko, Rappe, PRL 100, 256101 (2008)